## BSV52LT1G

## Switching Transistor

## NPN Silicon

## Features

- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Emitter Voltage | $\mathrm{V}_{\mathrm{CEO}}$ | 12 | Vdc |
| Collector-Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | 20 | Vdc |
| Collector Current - Continuous | $\mathrm{I}_{\mathrm{C}}$ | 100 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Total Device Dissipation FR-5 Board, | $\mathrm{P}_{\mathrm{D}}$ |  |  |
| (Note 1) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 225 | mW |
| Derate above $25^{\circ} \mathrm{C}$ |  | 1.8 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta J \mathrm{~A}}$ | 556 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Total Device Dissipation | $\mathrm{P}_{\mathrm{D}}$ |  |  |
| Alumina Substrate, (Note 2) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 300 | mW |
| Derate above $25^{\circ} \mathrm{C}$ |  | 2.4 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta J A}$ | 417 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction and Storage Temperature | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $F R-5=1.0 \times 0.75 \times 0.062 \mathrm{in}$.
2. Alumina $=0.4 \times 0.3 \times 0.024 \mathrm{in} .99 .5 \%$ alumina.

ON Semiconductor ${ }^{\circledR}$
www.onsemi.com
SOT-23 (TO-236)

MARKING DIAGRAM


B2 = Device Code
M = Date Code*

- = Pb-Free Package
(Note: Microdot may be in either location)
*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| BSV52LT1G | SOT-23 <br> (Pb-Free) | $3,000 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |
| Collector-Emitter Breakdown Voltage $\left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{mAdc}\right)$ | $\mathrm{V}_{\text {(BR)CEO }}$ | 12 | - | Vdc |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \quad\left(V_{C B}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right) \\ & \left(\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{~T}_{\mathrm{A}}=125^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{I}_{\text {CBO }}$ | - | $\begin{aligned} & 100 \\ & 5.0 \end{aligned}$ | nAdc <br> uAdc |

## ON CHARACTERISTICS

| $\begin{aligned} & \text { DC Current Gain } \\ & \left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=50 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \end{aligned}$ | $\mathrm{H}_{\text {FE }}$ | $\begin{aligned} & 25 \\ & 40 \\ & 25 \end{aligned}$ | $120$ | - |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Collector-Emitter Saturation Voltage } \\ & \left(I_{C}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=300 \mu \mathrm{Adc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=50 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{mAdc}\right) \end{aligned}$ | $\mathrm{V}_{\text {CE(sat) }}$ |  | $\begin{aligned} & 300 \\ & 250 \\ & 400 \end{aligned}$ | mVdc |
| $\begin{array}{r} \hline \text { Base-Emitter Saturation Voltage } \\ \left(I_{C}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{mAdc}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=50 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{mAdc}\right) \end{array}$ | $\mathrm{V}_{\mathrm{BE} \text { (sat) }}$ | 700 | $\begin{gathered} 850 \\ 1200 \end{gathered}$ | mVdc |

SMALL-SIGNAL CHARACTERISTICS

| Current-Gain - Bandwidth Product <br> $\left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=100 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 400 | - | MHz |
| :--- | :---: | :---: | :---: | :---: |
| Output Capacitance <br> $\left(\mathrm{V}_{\mathrm{CB}}=5.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\text {obo }}$ |  | p |  |
| Input Capacitance <br> $\left(\mathrm{V}_{\mathrm{EB}}=1.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\mathrm{ibo}}$ | - | 4.0 | pF |

SWITCHING CHARACTERISTICS

| Storage Time $\left(I_{\mathrm{C}}=\mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=10 \mathrm{mAdc}\right)$ | $\mathrm{t}_{\text {s }}$ | - | 13 | ns |
| :---: | :---: | :---: | :---: | :---: |
| Turn-On Time $\left(\mathrm{V}_{\mathrm{BE}}=1.5 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=3.0 \mathrm{mAdc}\right)$ | $\mathrm{t}_{\text {on }}$ | - | 12 | ns |
| Turn-Off Time $\left(I_{C}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=3.0 \mathrm{mAdc}\right)$ | $\mathrm{t}_{\text {off }}$ | - | 18 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.


SOT-23 (TO-236)
CASE 318-08
ISSUE AS
DATE 30 JAN 2018

## SCALE 4:1



NOTES:
IMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | MILLIMETERS |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| $\mathbf{c}$ | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| $\mathbf{H E}_{\mathbf{E}}$ | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| T | $0^{\circ}$ | --- | $10^{\circ}$ | $0^{\circ}$ | --- | $10^{\circ}$ |

GENERIC
MARKING DIAGRAM*

RECOMMENDED SOLDERING FOOTPRINT



XXX = Specific Device Code
M = Date Code

- = Pb-Free Package
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " $\quad$ ", may or may not be present.


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